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RSY160P05

Transistors

4V Drive Pch MOSFET

RSY160P05

●Structure

Silicon P-channel MOSFET

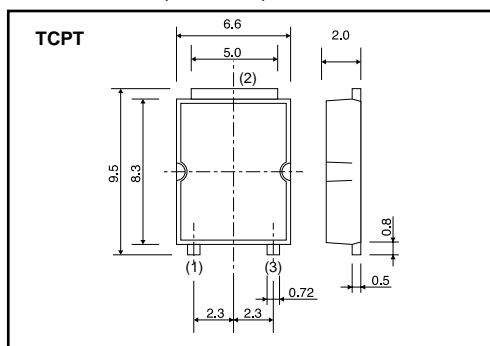
●Features

- 1) Low On-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Same land pattern as CPT3 (D-PAK).

●Application

Switching

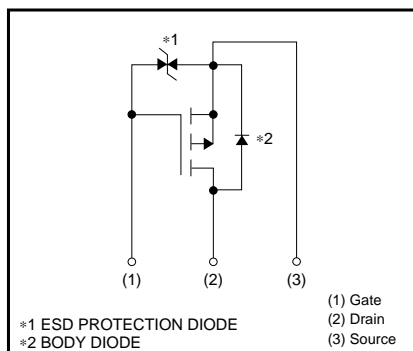
●Dimensions (Unit : mm)



●Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	2500
RSY160P05		○

●Equivalent circuit



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V _{DSS}	-45	V	
Gate-source voltage	V _{GSS}	±20	V	
Drain current	Continuous	I _D	±16	A
	Pulsed	I _{DP} *1	±32	A
Source current (Body diode)	Continuous	I _S	-16	A
	Pulsed	I _{SP} *1	-32	A
Total power dissipation	P _D *2	20	W	
Channel temperature	T _{ch}	150	°C	
Range of Storage temperature	T _{stg}	-55 to +150	°C	

*1 Pw≤10μs, Duty cycle≤1%

*2 Tc=25°C

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	R _{th} (ch-c) *	6.25	°C / W

* Tc=25°C

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●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	–	–	± 10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR) DSS}$	–45	–	–	V	$I_D = -1mA, V_{GS} = 0V$
Zero gate voltage drain current	I_{DSS}	–	–	–1	μA	$V_{DS} = -45V, V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	–1.0	–	–2.5	V	$V_{DS} = -10V, I_D = -1mA$
Static drain-source on-state resistance	$R_{DS(on)}$ *	–	35	50	$m\Omega$	$I_D = -16A, V_{GS} = -10V$
		–	45	63	$m\Omega$	$I_D = -8A, V_{GS} = -4.5V$
		–	50	70	$m\Omega$	$I_D = -8A, V_{GS} = -4.0V$
Forward transfer admittance	$ Y_{fs} $ *	8.5	–	–	S	$V_{DS} = -10V, I_D = -8A$
Input capacitance	C_{iss}	–	2150	–	pF	$V_{DS} = -10V$
Output capacitance	C_{oss}	–	250	–	pF	$V_{GS} = 0V$
Reverse transfer capacitance	C_{rss}	–	150	–	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}$ *	–	13	–	ns	$I_D = -10A$
Rise time	t_r *	–	30	–	ns	$V_{DD} = -25V$ $V_{GS} = -10V$
Turn-off delay time	$t_{d(off)}$ *	–	90	–	ns	$R_L = 2.5\Omega$
Fall time	t_f *	–	105	–	ns	$R_G = 10\Omega$
Total gate charge	Q_g *	–	17.0	25.5	nC	$V_{DD} = -25V, I_D = -10A$
Gate-source charge	Q_{gs} *	–	5.2	–	nC	$V_{GS} = -5V$
Gate-drain charge	Q_{gd} *	–	5.5	–	nC	$R_L = 2.5\Omega, R_G = 10\Omega$

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD} *	–	–	–1.2	V	$I_S = -16A, V_{GS} = 0V$

*Pulsed

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● **Electrical characteristic curves**

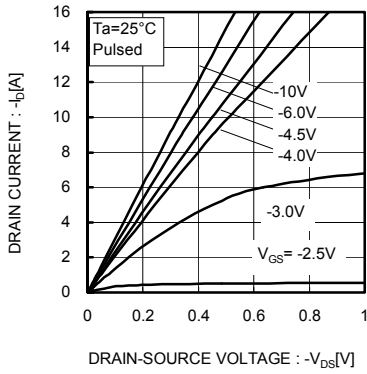


Fig.1 Typical Output Characteristics (I)

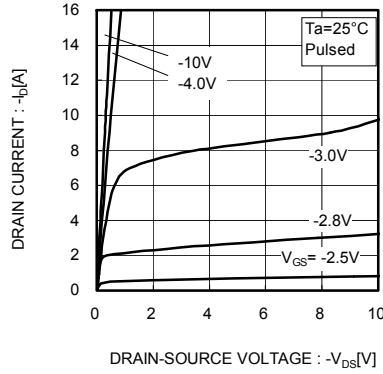


Fig.2 Typical Output Characteristics (II)

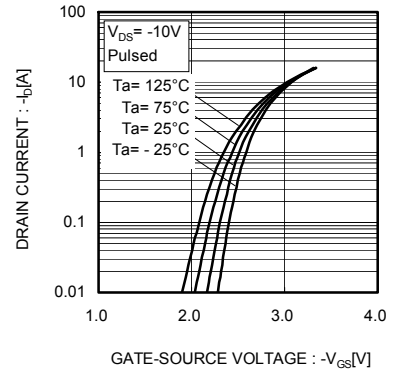


Fig.3 Typical Transfer Characteristics

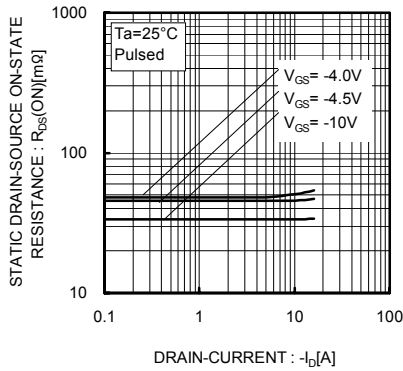


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current (I)

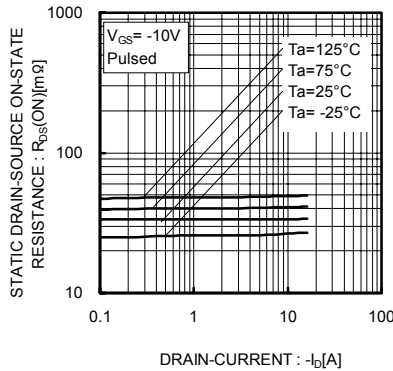


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current (II)

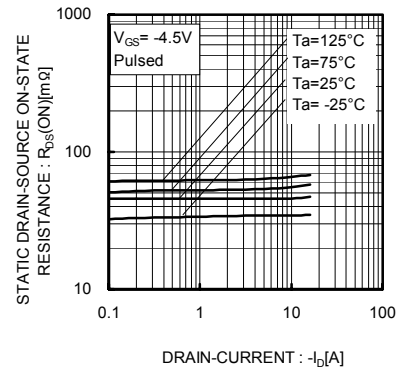


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current (III)

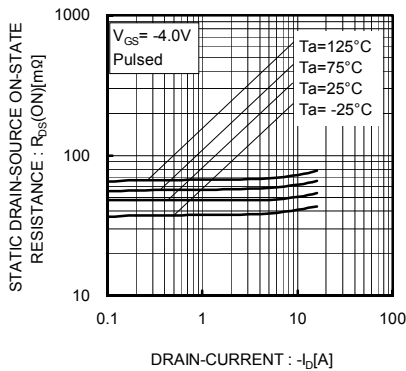


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current (IV)

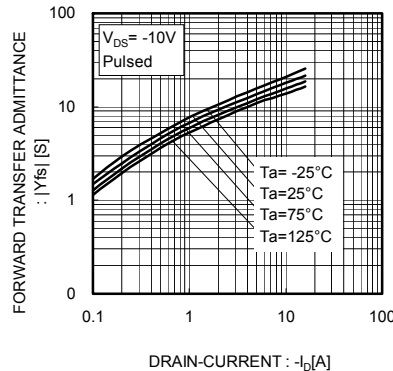


Fig.8 Forward Transfer Admittance vs. Drain Current

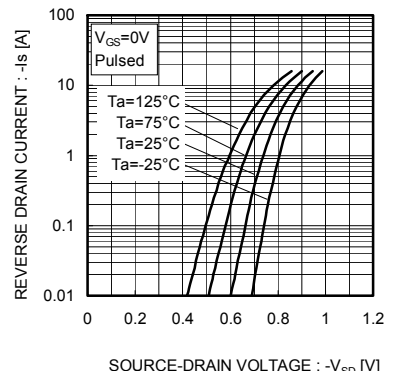


Fig.9 Reverse Drain Current vs. Source-Drain Voltage

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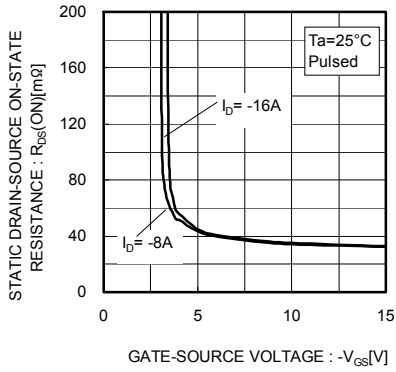


Fig.10 Static Drain-Source On-State Resistance vs. Gate Source

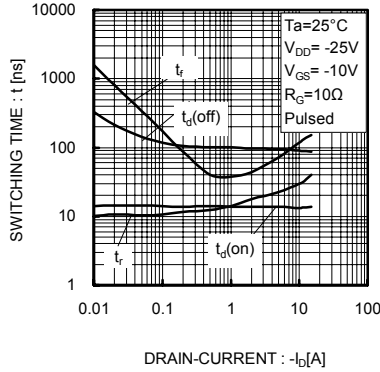


Fig.11 Switching Characteristics

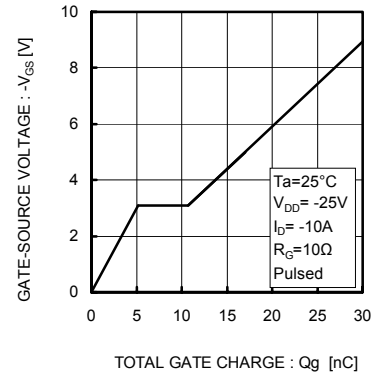


Fig.12 Dynamic Input Characteristics

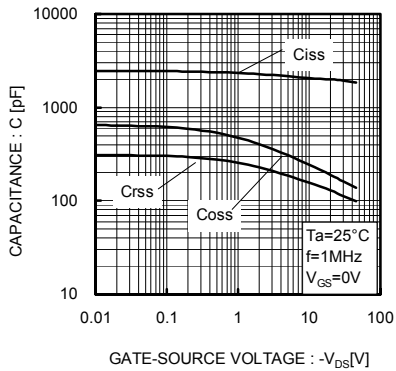


Fig.13 Typical Capacitance vs. Drain-Source Voltage

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● **Measurement circuits**

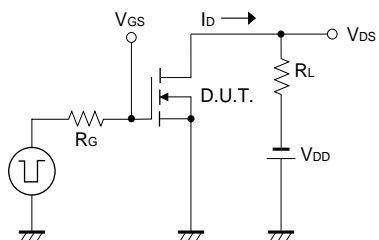


Fig.14 Switching Time Test Circuit

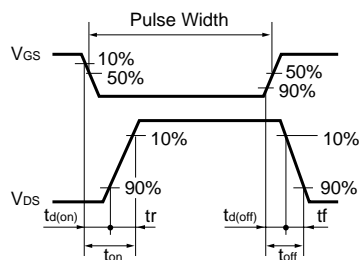


Fig.15 Switching Time Waveforms

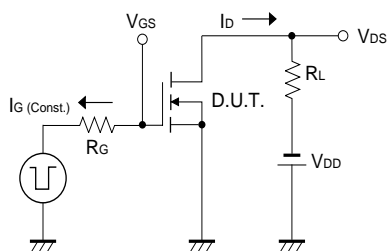


Fig.16 Gate Charge Test Circuit

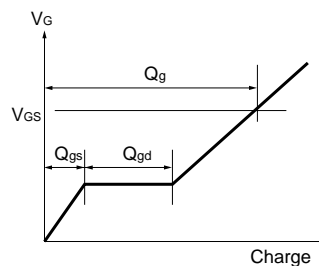


Fig.17 Gate Charge Waveform

Appendix

Notes

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